



0.8-6.0GHz, 30W, GaN Fully matched PA Module

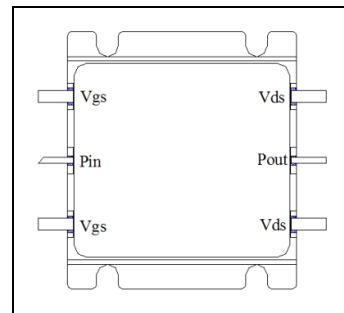
Description

The GMAH0860-30H3 is a 30-watt, single stage integrated Power Amplifier Module, designed for broad band applications, with frequencies from 0.8 to 6.0GHz. The module is 50 Ω input/output matched and requires minimal external components.

When used at higher voltage like 32V, it can deliver 40W across the full band

The module implements multiple GaN active dice and its matching network within highly compact 30.8*27.4mm metal RF package with excellent capability for heat dissipation.

Recommended driver: G2MAH0160-8



Product Features

- Operating Frequency Range: 0.8-6.0GHz
- Operating Drain Voltage(Recommended): +28 to 32V
- 50 Ω Input/Output (External DC block capacitor needed)
- $P_{sat} \geq 30W$ (CW) @28V, 40W (CW) at 32V
- Small signal gain: >13dB,
- Efficiency at P_{sat} : 40%
- IM3 at 39dBm output: <-25dBc with 1MHz tone spacing
- 30.8*27.4 mm metal RF package
- Compliant to Restriction of Hazardous Substances (RoHS) Directive 2002/95/EC

Applications

- Ultra Broadband Amplifiers within L band
- Test Instrumentation
- EMC Amplifier Drivers
- 2-way Radios

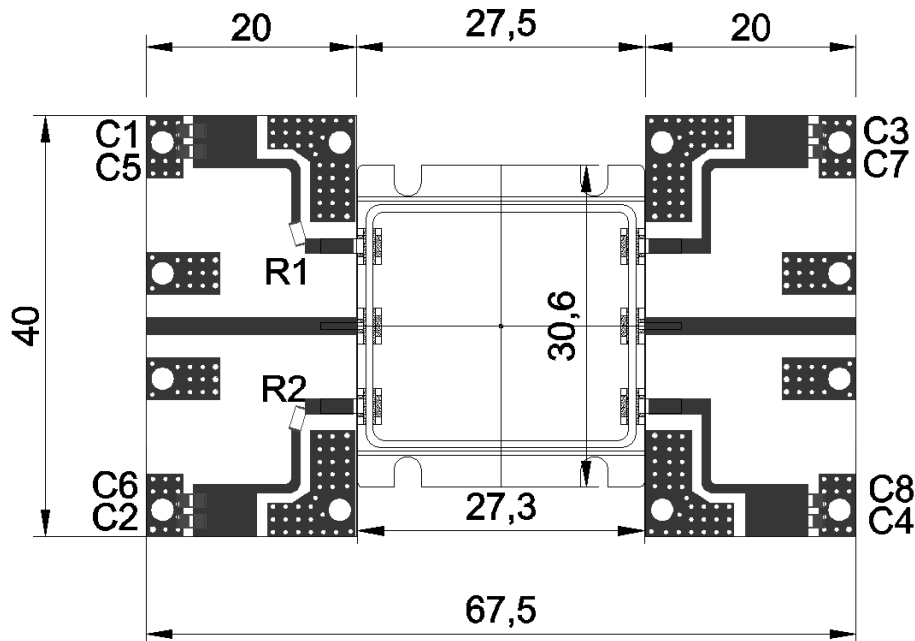
Table 1. Maximum Ratings

Rating	Symbol	Value	Unit
Drain--Source Voltage	V_{DS}	150	Vdc
Gate--Source Voltage	V_{GS}	-10 to +2	Vdc
Operating Voltage	V_{DO}	+32	Vdc
Storage Temperature Range	T_{stg}	-65 to +150	$^{\circ}C$
Case Operating Temperature	T_c	+150	$^{\circ}C$
Operating Junction Temperature	T_j	+225	$^{\circ}C$

Table 2. Thermal Characteristics

Characteristic	Symbol	Value	Unit
Thermal Resistance, Junction to Case $T_c = 25^{\circ}C$, $P_{out} = 30W$, FEA	$R_{\theta JC}$	2.4	$^{\circ}C/W$

Typical application circuit



Component	Description	Suggestion
C1 C2 C3 C4	10 uF	1210
C5 C6 C7 C8	82 pF	MQ301111
R1 R2	10 Ohm	1206
PCB	30Mil Rogers 4350	

TYPICAL CHARACTERISTICS

Figure 1. Network analyzer output S11/S21 (Pin=0dBm, Idq=200mA)

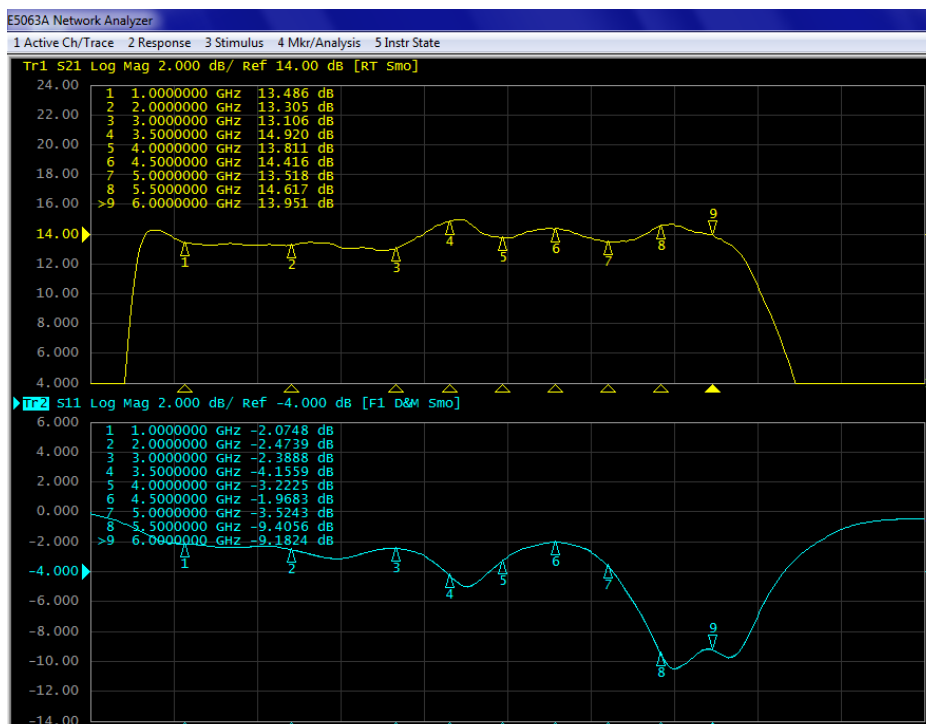




Figure 3. Psat, Eff, Gain Vs Frequency across the band @28V

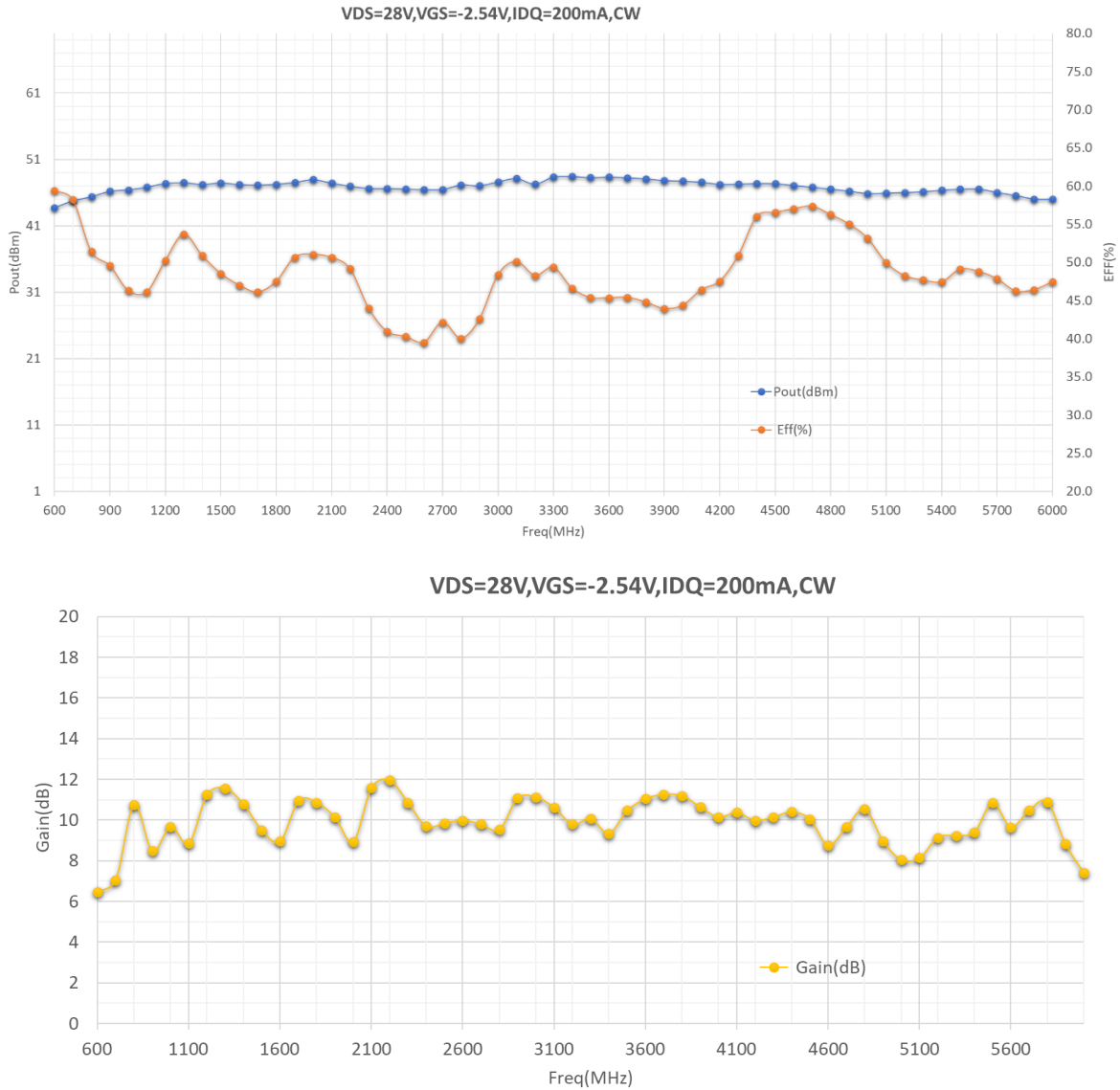
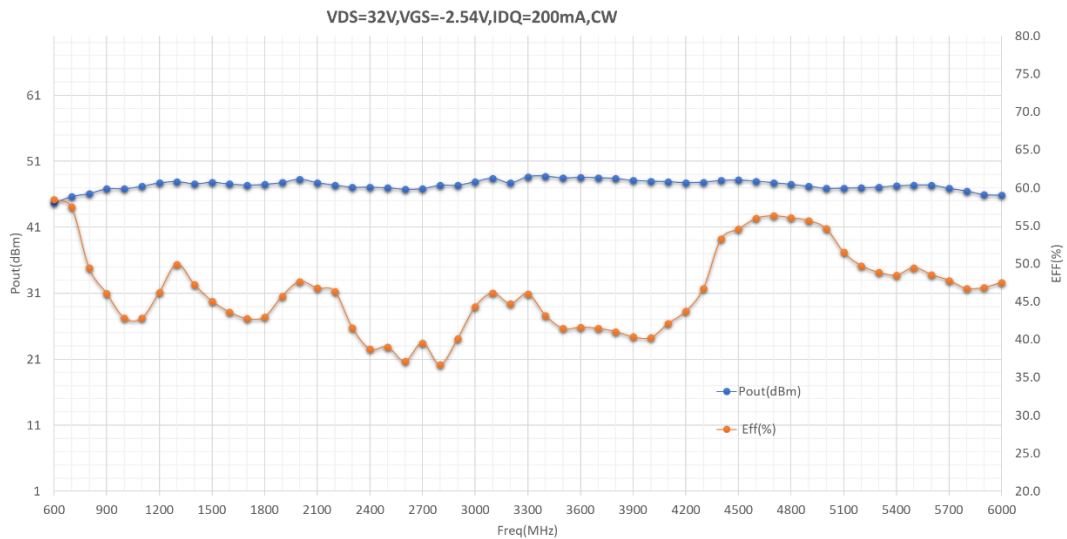


Figure 4. Psat, Eff, Gain Vs Frequency across the band @ 32V



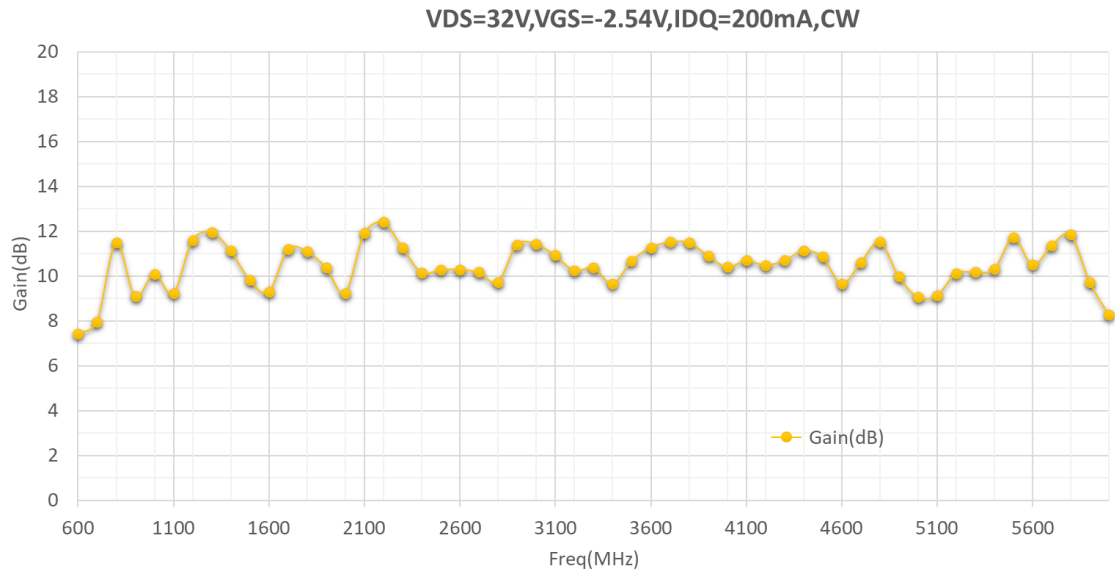
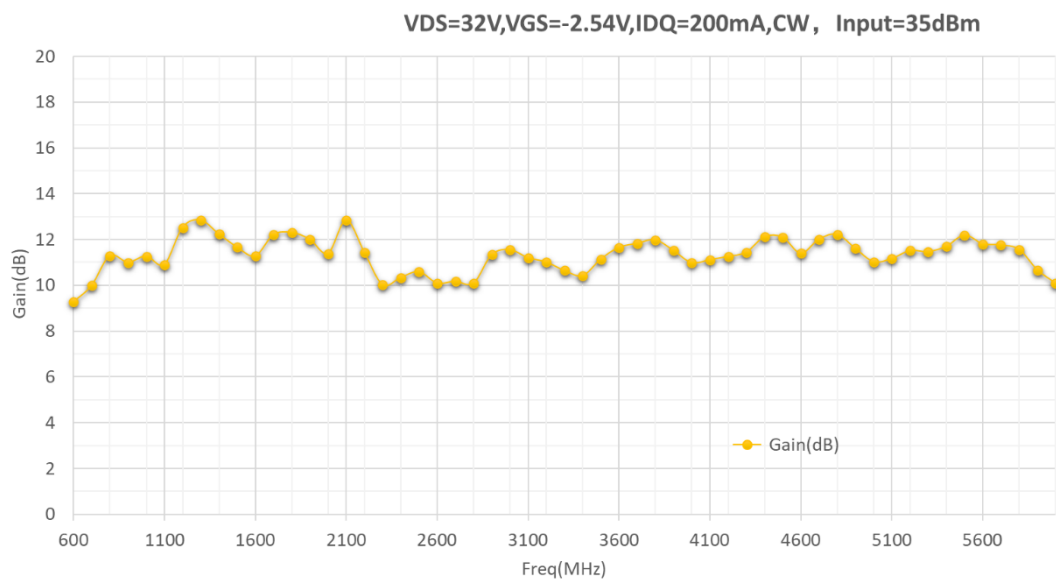
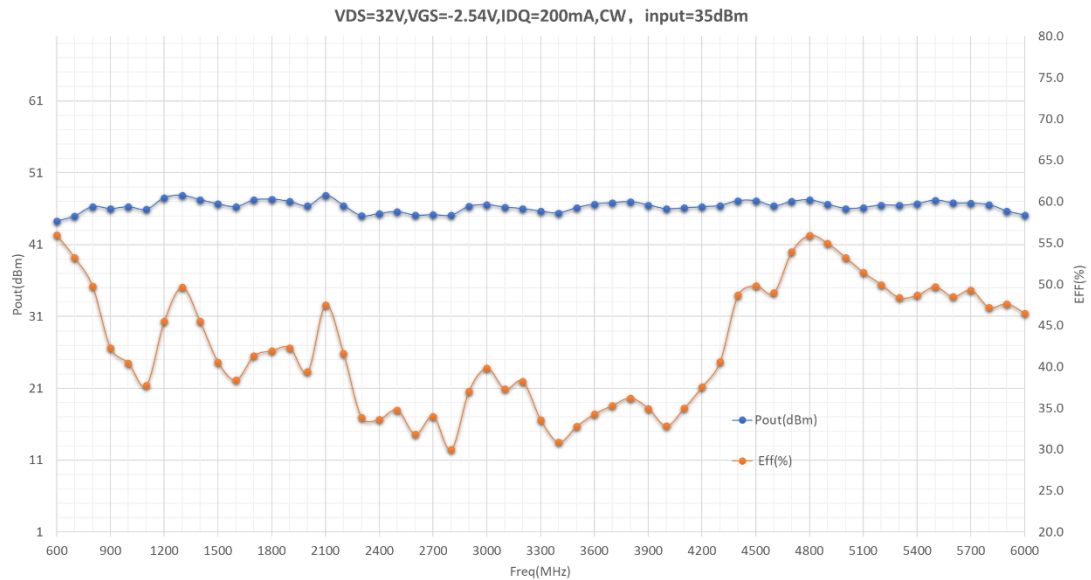
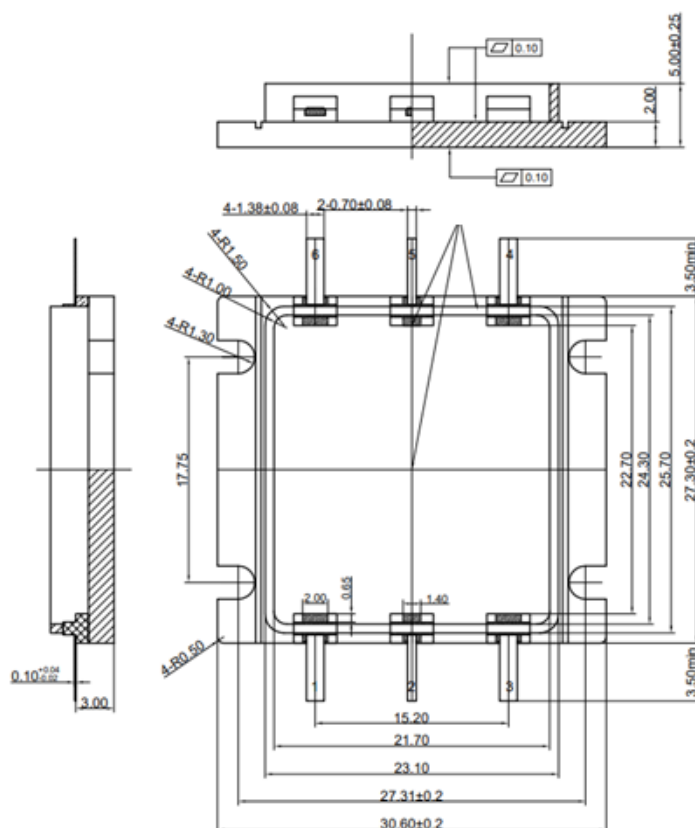


Figure 5. Pout, Eff, Gain Vs Frequency across the band @ 32V Pin=35dBm



Package Dimensions (Unit:mm)



Revision history

Table 6. Document revision history

Date	Revision	Datasheet Status
2024/11/16	Rev 1.0	Advanced Datasheet

Application data based on JF-24-11

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